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April 2015

# FGH60N60UFDTU\_F085

## 600V, 60A Field Stop IGBT



### Features

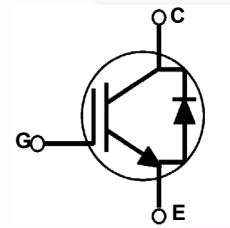
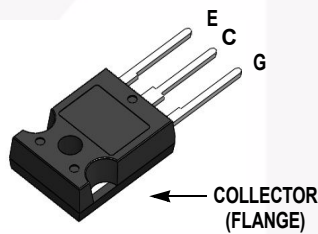
- High Current Capability
- Low Saturation Voltage:  $V_{CE(sat)} = 1.8\text{ V @ } I_C = 60\text{ A}$
- High Input Impedance
- Fast Switching
- RoHS Compliant
- Qualified to Automotive Requirements of AEC-Q101

### General Description

Using Novel Field Stop IGBT Technology, Fairchild's new series of Field Stop IGBTs offer the optimum performance for Automotive Chargers, Inverter, and other applications where low conduction and switching losses are essential.

### Applications

- Automotive chargers, Converters, High Voltage Auxiliaries
- Inverters, PFC, UPS



### Absolute Maximum Ratings

Symbol	Description	Ratings	Unit
$V_{CES}$	Collector to Emitter Voltage	600	V
$V_{GES}$	Gate to Emitter Voltage	$\pm 20$	V
	Transient Gate-to-Emitter Voltage	$\pm 30$	
$I_C$	Collector Current @ $T_C = 25^\circ\text{C}$	120	A
	Collector Current @ $T_C = 100^\circ\text{C}$	60	A
$I_{CM(1)}$	Pulsed Collector Current @ $T_C = 25^\circ\text{C}$	180	A
$P_D$	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	298	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	119	
$T_J$	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_L$	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

**Notes:**

1: Repetitive test, Pulse width limited by max. junction temperature

### Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}(\text{IGBT})$	Thermal Resistance, Junction to Case	0.33	$^\circ\text{C/W}$
$R_{\theta JC}(\text{Diode})$	Thermal Resistance, Junction to Case	1.1	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	40	$^\circ\text{C/W}$

FGH60N60UFDTU\_F085 — 600V, 60A Field Stop IGBT

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH60N60UFDTU_F085	FGH60N60UFD	TO-247	Tube	N/A	N/A	30

## Electrical Characteristics of the IGBT T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
<b>Off Characteristics</b>						
$BV_{CES}$	Collector to Emitter Breakdown Voltage	$V_{GE} = 0\text{ V}, I_C = 250\ \mu\text{A}$	600	-	-	V
$\Delta BV_{CES} / \Delta T_J$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0\text{ V}, I_C = 250\ \mu\text{A}$	-	0.67	-	V/°C
$I_{CES}$	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0\text{ V}$	-	-	250	$\mu\text{A}$
$I_{GES}$	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0\text{ V}$	-	-	±400	nA
<b>On Characteristics</b>						
$V_{GE(th)}$	G-E Threshold Voltage	$I_C = 250\ \mu\text{A}, V_{CE} = V_{GE}$	4.0	5.0	6.5	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	$I_C = 60\text{ A}, V_{GE} = 15\text{ V}$	-	1.8	2.9	V
		$I_C = 60\text{ A}, V_{GE} = 15\text{ V}, T_C = 125^\circ\text{C}$	-	2.1	-	V
<b>Dynamic Characteristics</b>						
$C_{ies}$	Input Capacitance	$V_{CE} = 30\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$	-	2540	-	pF
$C_{oes}$	Output Capacitance		-	330	-	pF
$C_{res}$	Reverse Transfer Capacitance		-	110	-	pF
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400\text{ V}, I_C = 60\text{ A}, R_G = 5\ \Omega, V_{GE} = 15\text{ V},$ Inductive Load, $T_C = 25^\circ\text{C}$	-	29	-	ns
$t_r$	Rise Time		-	60	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	138	-	ns
$t_f$	Fall Time		-	28	80	ns
$E_{on}$	Turn-On Switching Loss		-	2.47	-	mJ
$E_{off}$	Turn-Off Switching Loss		-	0.81	-	mJ
$E_{ts}$	Total Switching Loss		-	3.28	-	mJ
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400\text{ V}, I_C = 60\text{ A}, R_G = 5\ \Omega, V_{GE} = 15\text{ V},$ Inductive Load, $T_C = 125^\circ\text{C}$	-	28	-	ns
$t_r$	Rise Time		-	55	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	147	-	ns
$t_f$	Fall Time		-	71	-	ns
$E_{on}$	Turn-On Switching Loss		-	3.01	-	mJ
$E_{off}$	Turn-Off Switching Loss		-	1.21	-	mJ
$E_{ts}$	Total Switching Loss		-	4.22	-	mJ
$Q_g$	Total Gate Charge	$V_{CE} = 400\text{ V}, I_C = 60\text{ A}, V_{GE} = 15\text{ V}$	-	192	-	nC
$Q_{ge}$	Gate to Emitter Charge		-	24	-	nC
$Q_{gc}$	Gate to Collector Charge		-	102	-	nC

**Electrical Characteristics of the Diode** T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max	Units	
V <sub>FM</sub>	Diode Forward Voltage	I <sub>F</sub> = 30 A	T <sub>C</sub> = 25°C	-	1.70	2.6	V
			T <sub>C</sub> = 125°C	-	1.54	-	
t <sub>rr</sub>	Diode Reverse Recovery Time	I <sub>F</sub> = 30 A, di <sub>F</sub> /dt = 200 A/μs	T <sub>C</sub> = 25°C	-	76	-	ns
			T <sub>C</sub> = 125°C	-	242	-	
Q <sub>rr</sub>	Diode Reverse Recovery Charge	I <sub>F</sub> = 30 A, di <sub>F</sub> /dt = 200 A/μs	T <sub>C</sub> = 25°C	-	208	-	nC
			T <sub>C</sub> = 125°C	-	1162	-	



## Typical Performance Characteristics

Figure 1. Typical Output Characteristics

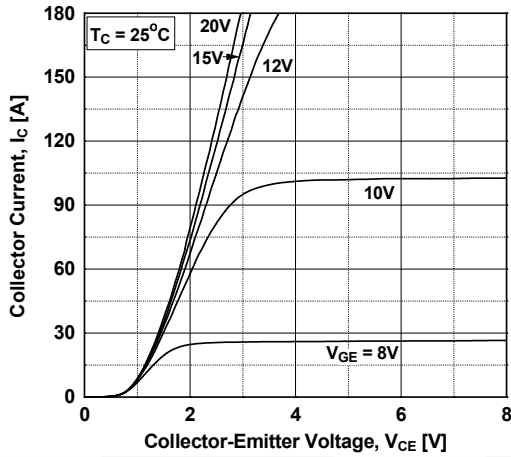


Figure 2. Typical Output Characteristics

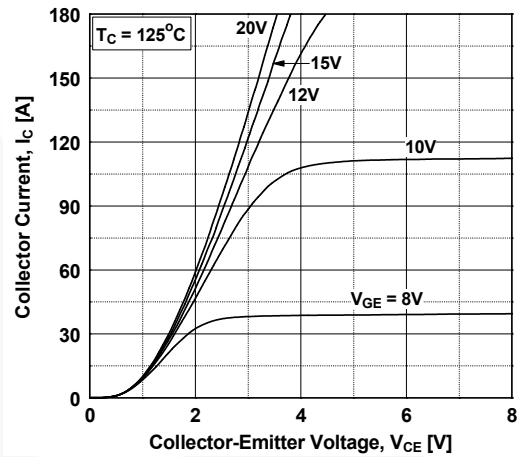


Figure 3. Typical Saturation Voltage Characteristics

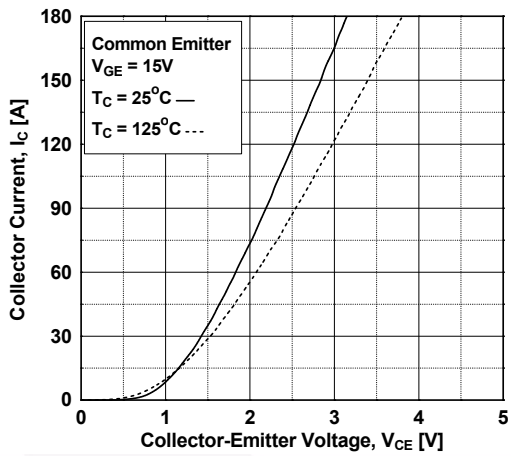


Figure 4. Transfer Characteristics

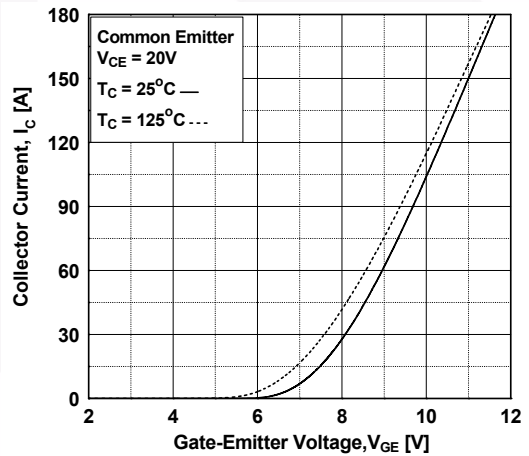


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

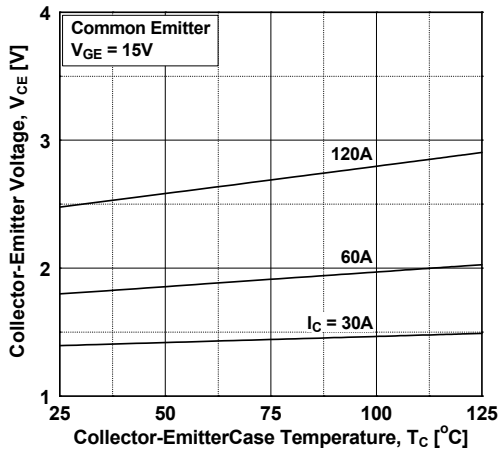
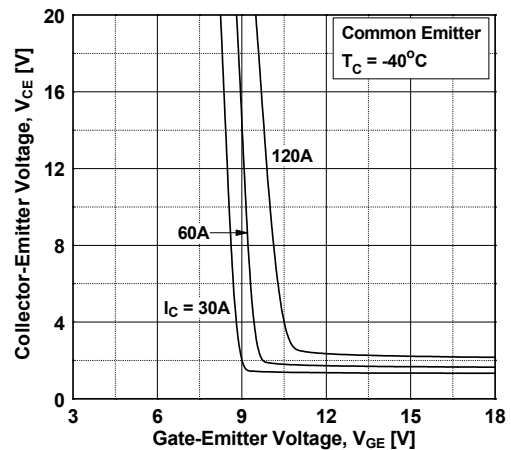


Figure 6. Saturation Voltage vs. Vge



## Typical Performance Characteristics

Figure 7. Saturation Voltage vs.  $V_{GE}$

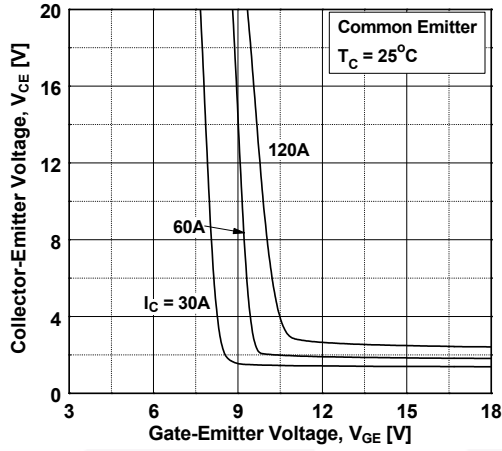


Figure 8. Saturation Voltage vs.  $V_{GE}$

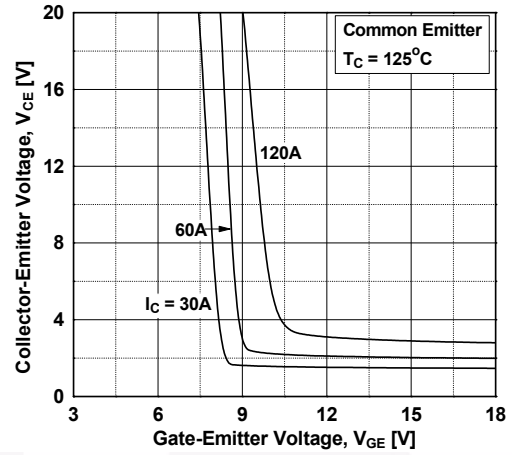


Figure 9. Capacitance Characteristics

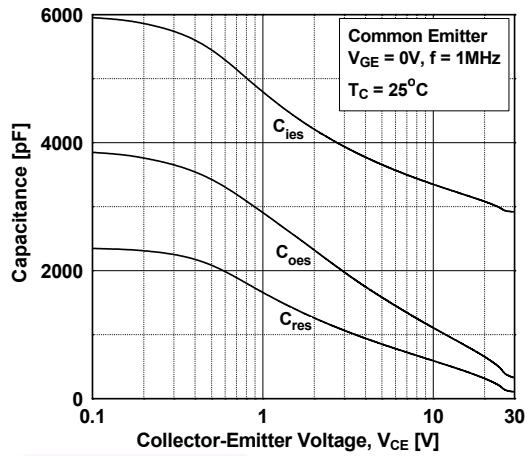


Figure 10. Gate charge Characteristics

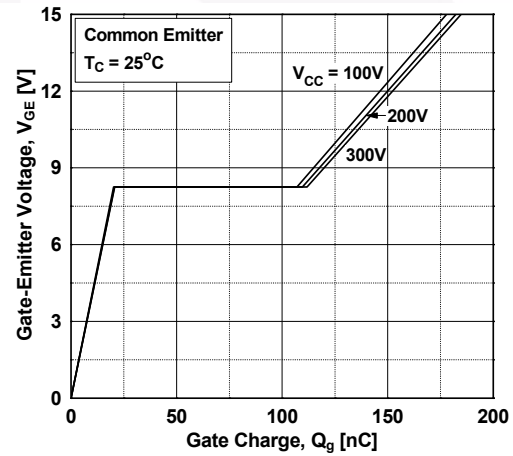


Figure 11. SOA Characteristics Characteristics

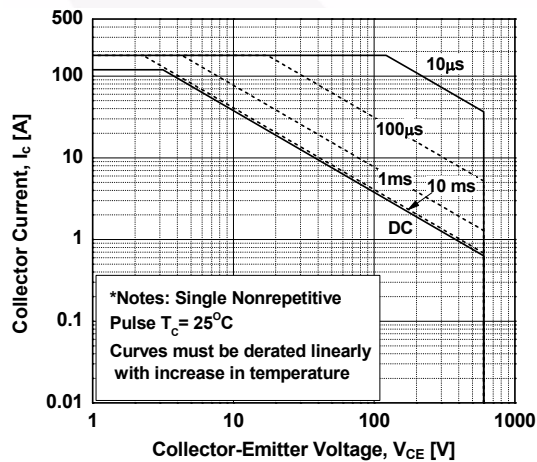
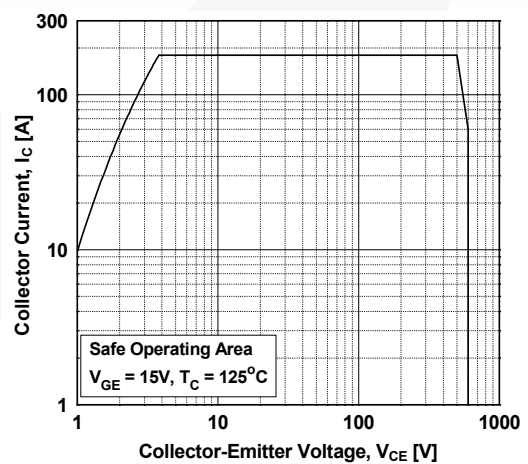
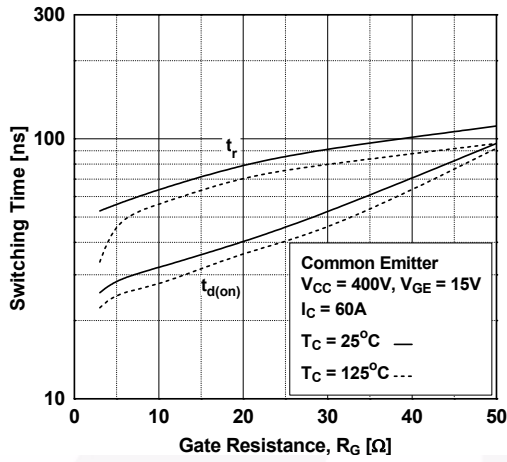


Figure 12. Turn off Switching SOA

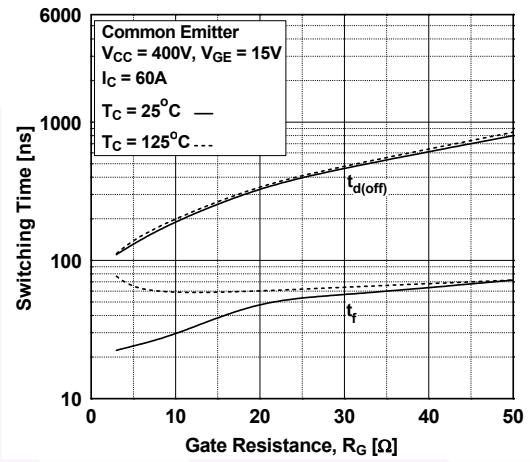


## Typical Performance Characteristics

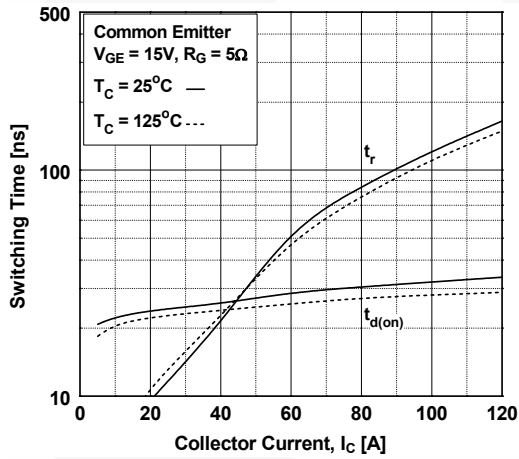
**Figure 13. Turn-on Characteristics vs. Gate Resistance**



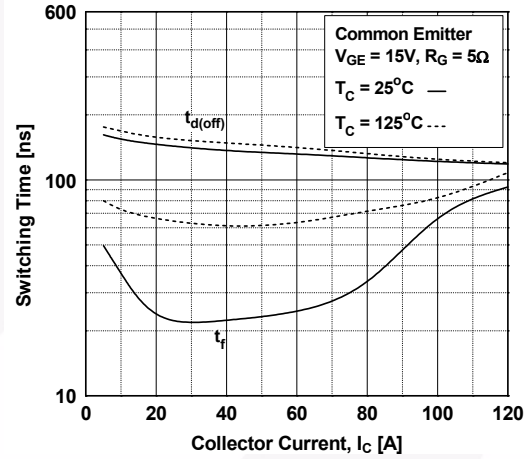
**Figure 14. Turn-off Characteristics vs. Gate Resistance**



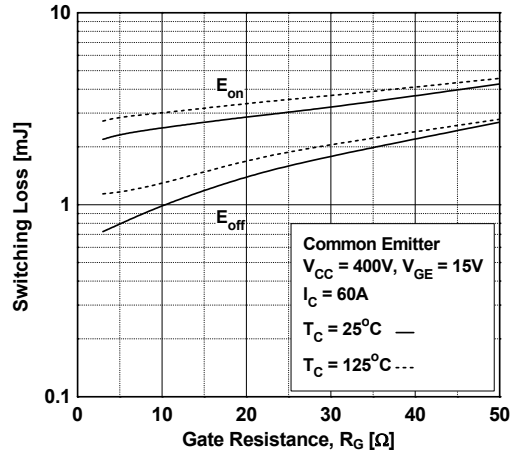
**Figure 15. Turn-on Characteristics vs. Collector Current**



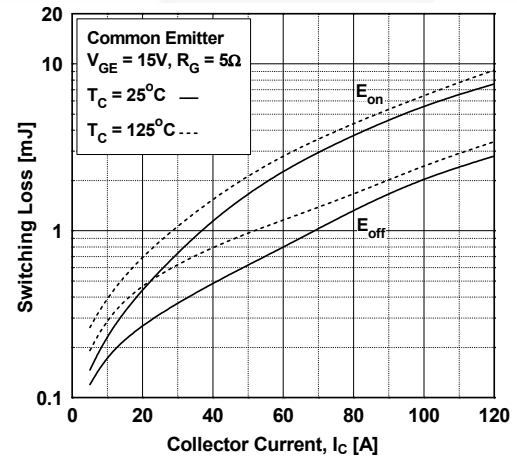
**Figure 16. Turn-off Characteristics vs. Collector Current**



**Figure 17. Switching Loss vs. Gate Resistance**



**Figure 18. Switching Loss vs. Collector Current**



## Typical Performance Characteristics

Figure 19. Forward Characteristics

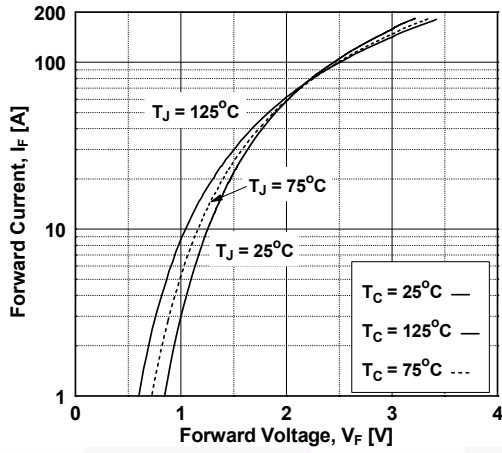


Figure 20. Reverse Current

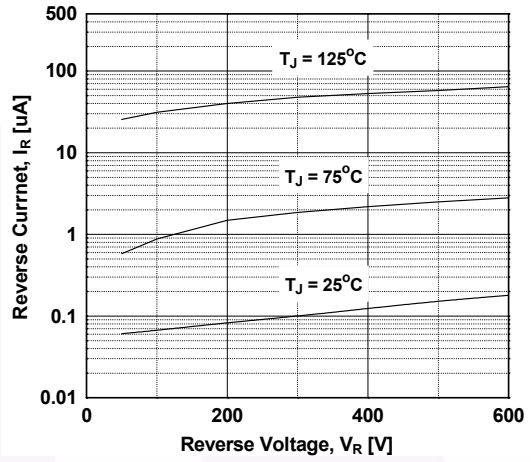


Figure 21. Stored Charge

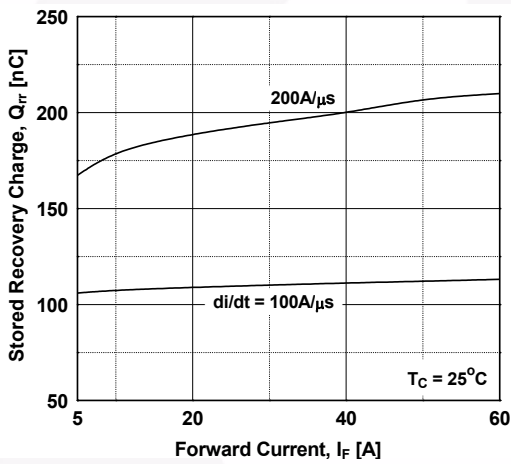


Figure 22. Reverse Recovery Time

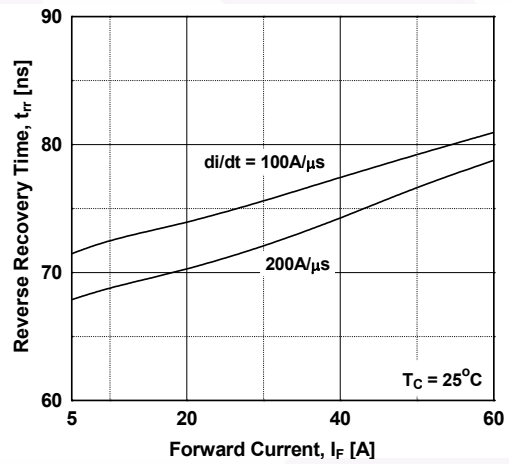
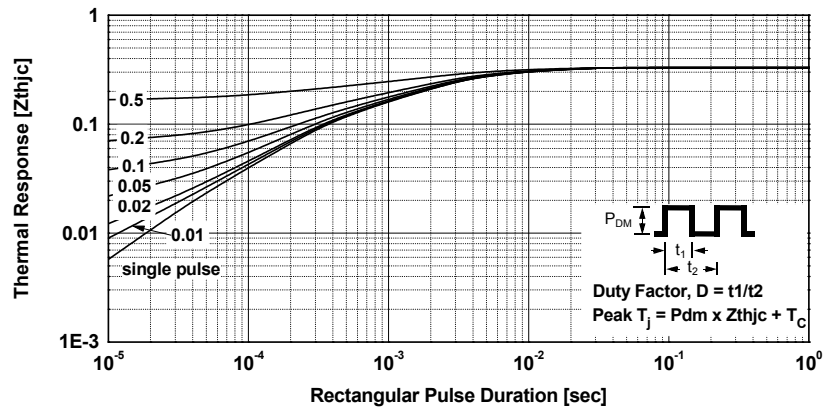
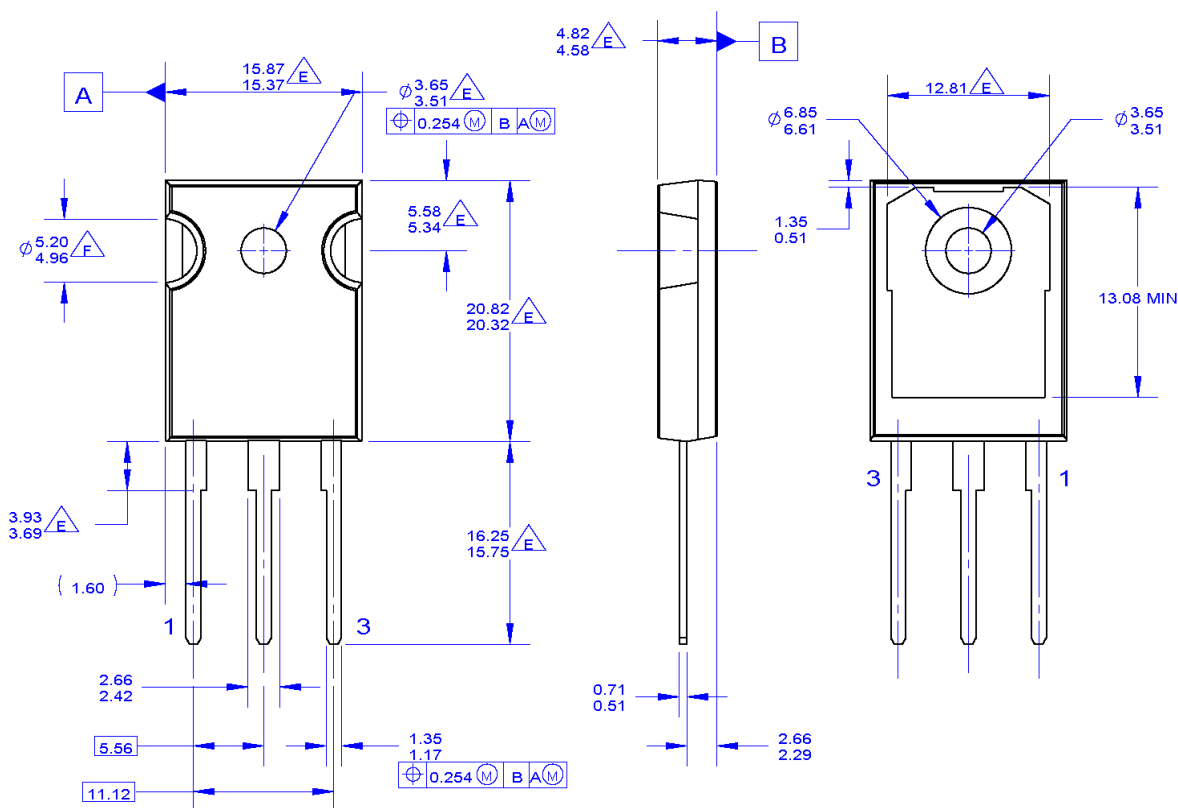


Figure 23. Transient Thermal Impedance of IGBT







## Mechanical Dimensions



NOTES: UNLESS OTHERWISE SPECIFIED.

- A. PACKAGE REFERENCE: JEDEC TO-247, ISSUE E, VARIATION AB, DATED JUNE, 2004.
- B. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- C. ALL DIMENSIONS ARE IN MILLIMETERS.
- D. DRAWING CONFORMS TO ASME Y14.5 - 1994
-  DOES NOT COMPLY JEDEC STANDARD VALUE
-  NOTCH MAY BE SQUARE
- G. DRAWING FILENAME: MKT-TO247A03\_REV03

**Figure 24. TO-247 3L - TO-247,MOLDED,3 LEAD,JEDEC VARIATION AB**

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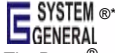

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- SuperFET®
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- SuperSOT™-6
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